

Absolute Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-40	V
Collector-Emitter Voltage	V _{CEO}	-40	V
Emitter-Base Voltage	V _{EBO}	-5	V
Peak Pulse Collector Current	I _{CM}	-3	Α
Continuous Collector Current	Ic	-2	А
Base Current	I _B	-300	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	730	mW
Power Dissipation (Note 6)	P _D	600	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	171	°C/W
Thermal Resistance, Junction to Ambient Air (Note 6)	R _{θJA}	209	°C/W
Thermal Resistance, Junction to Lead (Note 7)	$R_{ heta JL}$	75	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

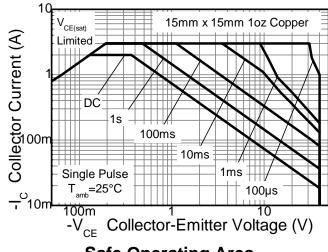
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

- 5. For a device mounted with the collector lead on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is mounted on minimum recommended pad layout.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

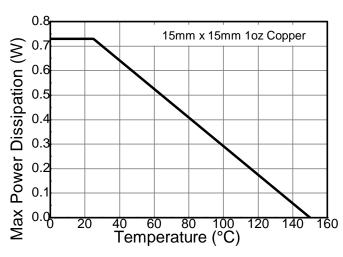
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



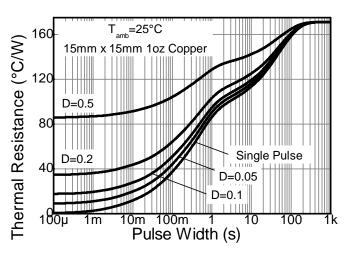
Thermal Characteristics and Derating Information



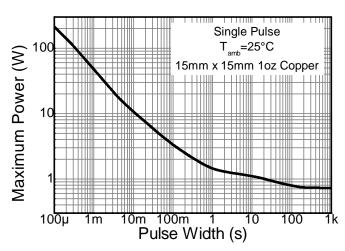
Safe Operating Area



Derating Curve



Transient Thermal Impedance



Pulse Power Dissipation

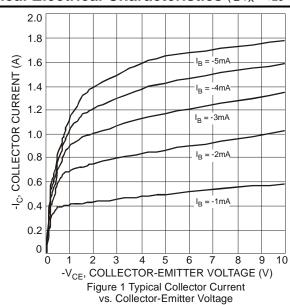


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
OFF CHARACTERISTICS	1 -			u.	I.	-
Collector-Base Breakdown Voltage	BV _{CBO}	-40	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-40	_	_	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-5	_	_	V	I _E = -100μA
Collector-Base Cutoff Current		_	_	-100	nA	$V_{CB} = -30V, I_{E} = 0$
Collector-Base Cuton Current	Ісво	_	_	-50	μΑ	$V_{CB} = -30V$, $I_E = 0$, $T_A = +150$ °C
Emitter-Base Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -4V, I _C = 0
ON CHARACTERISTICS (Note 9)						•
		300	_	_		$V_{CE} = -2V, I_{C} = -0.1A$
DC Current Gain	h	260	_	_		$V_{CE} = -2V, I_{C} = -0.5A$
DC Current Gain	h _{FE}	210	_	_		$V_{CE} = -2V, I_{C} = -1A$
		100	_	_		$V_{CE} = -2V$, $I_C = -2A$
		_	_	-100		$I_C = -100 \text{mA}, I_B = -1 \text{mA}$
		_	-45	-110	mV	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	-225		$I_C = -750 \text{mA}, I_B = -15 \text{mA}$
		_	_	-225		$I_C = -1A$, $I_B = -50mA$
		_	_	-350		$I_C = -2A$, $I_B = -200mA$
Equivalent On-Resistance	R _{CE(SAT)}	_	90	220	mΩ	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	_	-1.1	V	$I_C = -2A$, $I_B = -200mA$
Base-Emitter Turn-On Voltage	V _{BE(ON)}	_	_	-0.75	V	$V_{CE} = -2V, I_{C} = -100mA$
SMALL SIGNAL CHARACTERISTICS						•
	t _D	_	21	_	ns V _{CC}	
Switching times	t _R	_	22	_		$V_{CC} = -10V,$ $I_{C} = -500mA,$ $I_{B1} = I_{B2} = -50mA$
Switching times	ts	_	120	_		
	t _F	_	23	_		51 52 55
Transition Frequency	f⊤	100	_	_	MHz	$V_{CE} = -10V, I_{C} = -100mA,$ f = 100MHz
Output Capacitance	СОВ	_	_	28	pF	V _{CB} = -10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



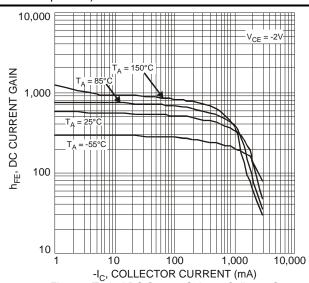


Figure 2 Typical DC Current Gain vs. Collector Current



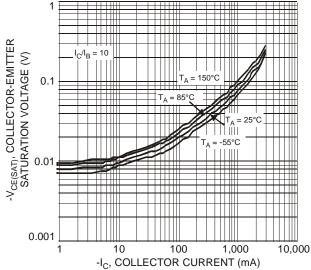


Figure 3 Typical Collector-Emitter Saturation Voltage vs. Collector Current

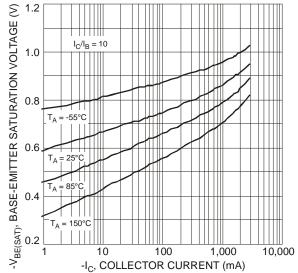


Figure 5 Typical Base-Emitter Saturation Voltage vs. Collector Current

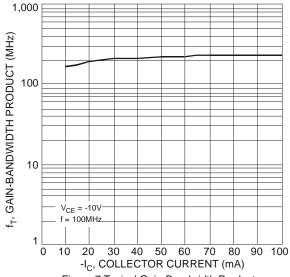


Figure 7 Typical Gain-Bandwidth Product vs. Collector Current

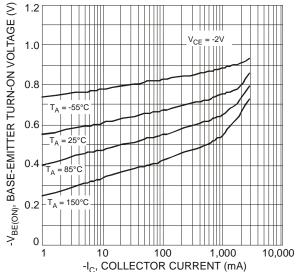


Figure 4 Typical Base-Emitter Turn-On Voltage vs. Collector Current

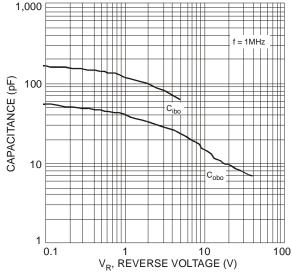


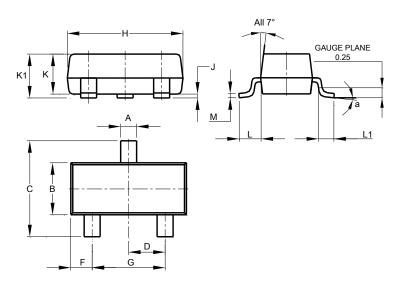
Figure 6 Typical Capacitance Characteristics



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

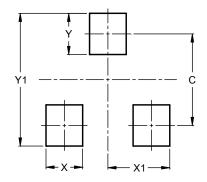


SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
C	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
J	0.013	0.10	0.05		
K	0.890	1.00	0.975		
K 1	0.903	1.10	1.025		
١	0.45	0.61	0.55		
L1	0.25	0.55	0.40		
М	0.085	0.150	0.110		
а	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



Dimensions	Value (in mm)
С	2.0
X	0.8
X1	1.35
Υ	0.9
Y1	2.9



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